

### **INCHANGE SEMICONDUCTOR**

# isc N-Channel MOSFET Transistor IPD70R950CE,IIPD70R950CE

#### FEATURES

- · Static drain-source on-resistance:
  - Ros(on)≤0.95Ω
- Enhancement mode:
- 100% avalanche tested
- · Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### DESCRITION

- · Fast switching
- · Very high commutation ruggedness

#### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	700	V
V <sub>GS</sub>	Gate-Source Voltage	±20	V
ID	Drain Current-Continuous	7.4	А
I <sub>DM</sub>	Drain Current-Single Pulsed	12	А
PD	Total Dissipation @T <sub>c</sub> =25°C	68	W
Tj	Max. Operating Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature	-40~150	°C

PARAMETER

Channel-to-case thermal resistance

Channel-to-ambient thermal resistance

MAX

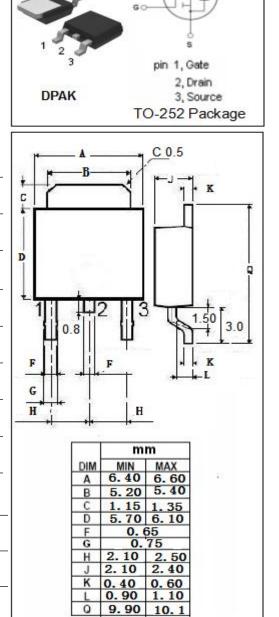
1.85

62

UNIT

°C/W

°C/W



#### isc website: www.iscsemi.cn

THERMAL CHARACTERISTICS

SYMBOL

Rth(j-c)

Rth(j-a)



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## IPD70R950CE,IIPD70R950CE

#### ELECTRICAL CHARACTERISTICS

T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =1mA	700			V
V <sub>GS</sub> (th)	Gate Threshold Voltage	VDS=VGS; ID=0.15mA	2.5		3.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =1.5A			0.95	Ω
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> =20V; V <sub>DS</sub> =0V			0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =700V; V <sub>GS</sub> = 0V			1	μA
V <sub>SD</sub>	Diode forward voltage	I <sub>F</sub> =2.2A, V <sub>GS</sub> = 0V		0.9		V

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